# **DMC201E0**

# Silicon NPN epitaxial planar type

For High frequency amplification

#### ■ Features

- ullet High transition frequency  $f_T$
- Contributes to miniaturization of sets, reduction of component count.
- Eco-friendly Halogen-free package

#### ■ Basic Part Number

Dual DSC2F01X (Common emitter)

#### Packaging

Embossed type (Thermo-compression sealing): 3000 pcs / reel (standard)

### ■ Absolute Maximum Ratings $T_a = 25$ °C

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	$V_{CBO}$	15	V	
Collector-emitter voltage (Base open)	$V_{CEO}$	10	V	
Emitter-base voltage (Collector open)	$V_{\mathrm{EBO}}$	3	V	
Collector current	$I_{C}$	50	mA	
Total power dissipation	P <sub>T</sub>	300	mW	
Junction temperature	$T_j$	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	

#### ■ Package

#### • Code

Mini5-G3-B

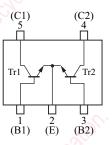
#### • Pin Name

1: Base (Tr1) 4: Collector (Tr2) 2: Emitter (Common) 5: Collector (Tr1)

3: Base (Tr2)

### ■ Marking Symbol: C7

#### Internal Connection



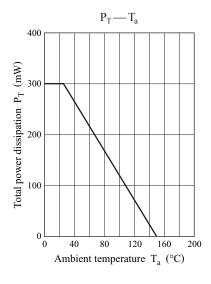
## ■ Electrical Characteristics $T_a = 25$ °C±3°C

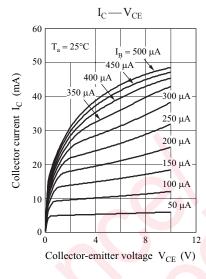
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_C = 2 \text{ mA}, I_B = 0$	10			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = 10 \mu A, I_C = 0$	3			V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = 10 \text{ V}, I_{E} = 0$			1	μΑ
Forward current transfer ratio	$h_{FE}$	$V_{CE} = 4 \text{ V}, I_{C} = 5 \text{ mA}$	75		220	_
h <sub>FE</sub> ratio *	h <sub>FE</sub> (Small/Large)	$V_{CE} = 4 \text{ V, } I_{C} = 5 \text{ mA}$	0.50	0.99		_
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_C = 20 \text{ mA}, I_B = 4 \text{ mA}$			0.5	V
Transition frequency	$f_T$	$V_{CE} = 4 \text{ V}, I_{C} = 5 \text{ mA}$		1.9		GHz
Collector output capacitance (Common base, input open circuited)	C <sub>ob</sub>	$V_{CB} = 4 \text{ V}, I_E = 0, f = 1 \text{ MHz}$		1.2		pF
Collector-base parameter	r <sub>bb</sub> '•C <sub>C</sub>	$V_{CE} = 4 \text{ V}, I_{C} = 5 \text{ mA}, f = 31.9 \text{ MHz}$		12		ps
Reverse transfer capacitance (Common base)	C <sub>rb</sub>	$V_{CE} = 4 \text{ V}, I_{C} = 0, f = 1 \text{ MHz}$		0.6		pF

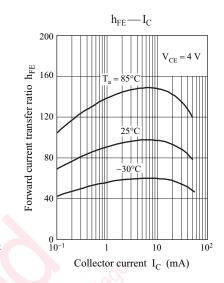
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

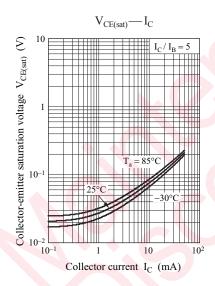
2. \*: Ratio between 2 elements

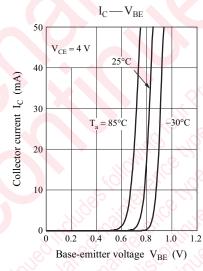
DMC201E0 Panasonic

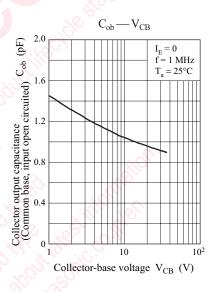


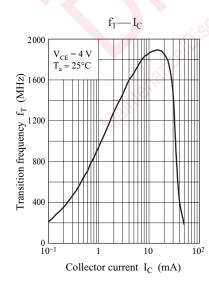






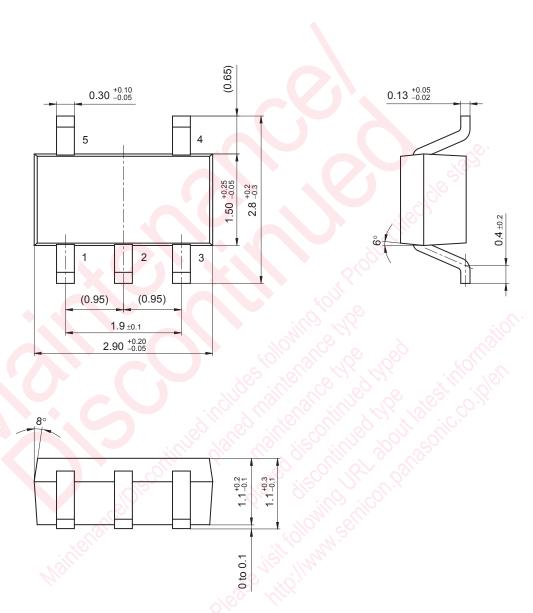






2 Ver. AED

Mini5-G3-B Unit: mm



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